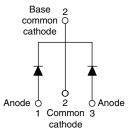


#### Vishay High Power Products

#### Ultrafast Rectifier, 2 x 10 A FRED Pt<sup>TM</sup>

# 2 x 10 A F





PRODUCT SUMMARY				
t <sub>rr</sub>	25 ns			
I <sub>F(AV)</sub>	2 x 10 A			
$V_{R}$	200 V			

#### **FEATURES**

- · Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Designed and qualified for industrial level

#### **DESCRIPTION/APPLICATIONS**

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage	V <sub>RRM</sub>		200	V	
per leg	IF(AV)		10	^	
Average rectified forward current total device		Rated V <sub>R</sub> , T <sub>C</sub> = 145 °C	20		
Non-repetitive peak surge current per leg	I <sub>FSM</sub>		100	А	
Peak repetitive forward current per leg	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 145 °C	20		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-		
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	-	0.85	V	
Forward voltage V	$V_{F}$	I <sub>F</sub> = 16 A	-	-	1.15		
		I <sub>F</sub> = 16 A, T <sub>J</sub> = 125 °C	-	-	1.05	,	
Daviere la clara a coment	$V_R = V_R$ rated	-	-	15	μΑ		
Reverse leakage current I <sub>R</sub>		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-			250
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	55	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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## **MUR2020CT**

## Vishay High Power Products

## Ultrafast Rectifier, $2 \times 10 \text{ A FRED Pt}^{TM}$



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt =$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A/}\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	35	-
		$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{REC} = 0.25 \text{ A}$		-	-	25	
		T <sub>J</sub> = 25 °C	$I_F = 10 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	21	-	ns
		T <sub>J</sub> = 125 °C		-	35	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.9	-	A
		T <sub>J</sub> = 125 °C		-	4.8	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	25	-	nC
		T <sub>J</sub> = 125 °C		=	78	=	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	2.5	
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	50	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-	
Mojest			-	2.0	-	g
Weight			-	0.07	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220AB		MUR2	2020CT	•

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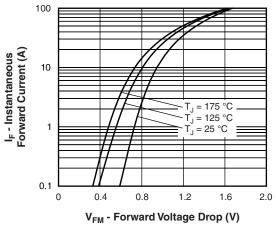


Fig. 1 - Maximum Forward Voltage Drop Characteristics

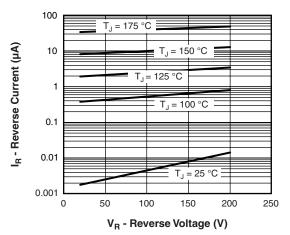


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

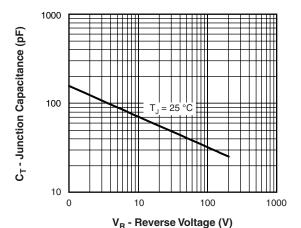


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

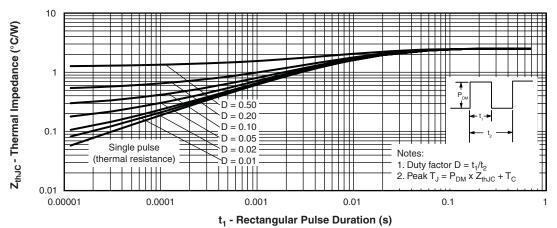
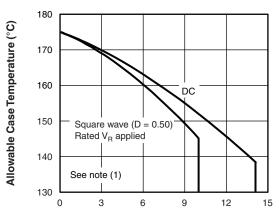


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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 $I_{F(AV)}$  - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

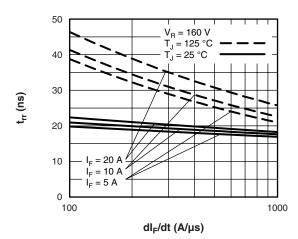


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

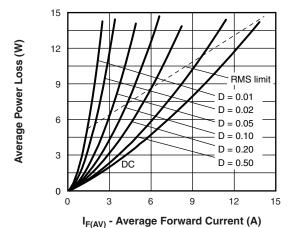


Fig. 6 - Forward Power Loss Characteristics

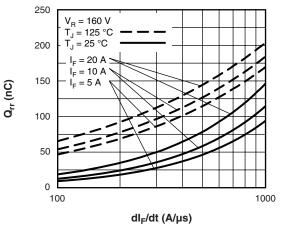


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{l} \text{(1) Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = Forward power loss = I_{F(AV)} \times V_{FM} \ at \ (I_{F(AV)}/D) \ (see fig. 6); \\ Pd_{REV} = Inverse power loss = V_{R1} \times I_R \ (1 - D); \ I_R \ at \ V_{R1} = Rated \ V_R \\ \end{array}$ 



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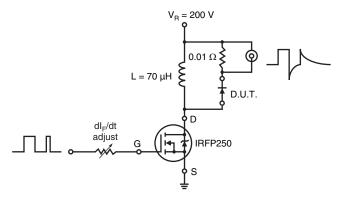
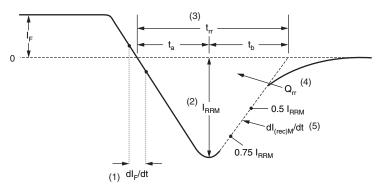


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{r}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dl_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

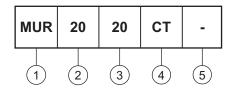
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#### **ORDERING INFORMATION TABLE**

Device code



- 1 Ultrafast MUR series
- 2 Current rating (20 = 20 A)
- **3** Voltage rating (20 = 200 V)
- CT = Center tap (dual)
- None = Standard production
  - PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS					
Dimensions	http://www.vishay.com/doc?95222				
Part marking information	http://www.vishay.com/doc?95225				
SPICE model	http://www.vishay.com/doc?95272				



Vishay

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